

Dimitrios Maroudas – List of PUBLICATIONS

1. D. Maroudas and R. A. Brown, "Diffusion of Point Defects in a Stressed Simple Cubic Crystal," in *Defects and Diffusion in Semiconductors: Bulk and Layered Structures*, edited by D. J. Wolford, J. Bernholc, and E. E. Haller, *Materials Research Society Symposia Proceedings*, vol. **163**, Materials Research Society, Pittsburgh (1990), pp. 615-620.
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5. D. Maroudas and R. A. Brown, "Model of Dislocation Locking by Oxygen Gettering in Silicon Crystals," *Applied Physics Letters* **58**, 1842-1844 (1991).
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12. D. Maroudas and S. T. Pantelides, "Theoretical Studies of Electromigration in Polycrystalline Metal Stripes," in *Materials Reliability in Microelectronics III*, edited by K. P. Rodbell, W. F. Filter, H. Frost, and P. S. Ho, *Materials Research Society Symposia Proceedings*, vol. **309**, Materials Research Society, Pittsburgh (1993), pp. 333-338.
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14. R. A. Brown, D. Maroudas, and T. Sinno, "Modeling Point Defect Dynamics in the Crystal Growth of Silicon," *Journal of Crystal Growth* **137**, 12-25 (1994).
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